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	Filing Date		2003-10-29
	First Named Inventor	Xunming Deng	
	Art Unit	1795	
	Examiner Name	Jeffrey Thomas Barton	
	Attorney Docket Number	1-25574	

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2	Bak, T.; Nowotny, J.; Rekas, M.; Sorrell, C.C., Photo-electrochemical hydrogen generation from water using solar energy, Materials-related aspects, Int. J. Hydrogen Energy, 27 (10), 2002, 991-1022.	<input type="checkbox"/>
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5	El-Shatter, Th.F., Eskandar, M.N., El-Hagry, M.T., Hybrid PV/fuel cell system design and simulation, Renewable Energy 27(2002) 479-485.	<input type="checkbox"/>
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13	Gao, X., Kocha, S., Frank, A.J., Turner, J.A, Photoelectrochemical decomposition of water using modified monolithic tandem cells, Int. J. of Hydrogen Energy, 24, 319325 (1999).	<input type="checkbox"/>
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